







SN54HCT04, SN74HCT04

SCLS042F - JULY 1986 - REVISED OCTOBER 2022

SNx4HCT04 Hex Inverters

1 Features

- Operating voltage range of 4.5V to 5.5V
- Outputs can drive up to 10 LSTTL loads
- Low power consumption, 20-µA max I_{CC}
- Typical t_{pd} = 13ns
- ±4-mA output drive at 5V
- Low input current of 1µA max
- Inputs are TTL-Voltage compatible

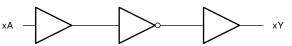
2 Description

These devices contain six independent inverters. They perform the Boolean function $Y = \overline{A}$ in positive logic.

Device Information(1)

_	• • • • • • • • • • • • • • • • • • • •	
PART NUMBER	PACKAGE	BODY SIZE (NOM)
SN74HCT04PW	TSSOP (14)	5.00 mm × 4.40 mm
SN74HCT04D	SOIC (14)	8.65 mm × 3.90 mm
SN74HCT04N	PDIP (14)	19.31 mm × 6.35 mm
SN74HCT04NSR	SO (14)	10.20 mm × 5.30 mm
SNJ54HCT04FK	LCCC (20)	8.89 mm × 8.89 mm
SNJ54HCT04J	CDIP (14)	19.55 mm × 6.71 mm

For all available packages, see the orderable addendum at the end of the data sheet.



Functional Block Diagram



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3 Revision History			

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision E (February 2022) to Revision F (October 2022)

Page

Changes from Revision D (July 2003) to Revision E (February 2022)

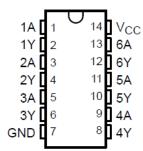
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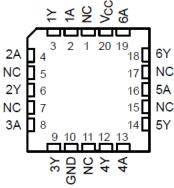
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4 Pin Configuration and Functions



J, D, N, NS, or PW Package 14-Pin CDIP, SOIC, PDIP, SO, or TSSOP Top View



FK Package 20-Pin LCCC Top View

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	7	V
I _{IK}	Input clamp current ⁽²⁾	$(V_1 < 0 \text{ or } V_1 > V_{CC})$		±20	mA
I _{OK}	Output clamp current ⁽²⁾	(V _O < 0 or V _O > V _{CC})		±20	mA
Io	Continuous output current	(V _O = 0 to V _{CC})		±25	mA
V _{CC} or GND	Continuous current through Vo	cc or GND		±50	mA
T _J	Junction temperature			150	°C
T _{stg}	Storage temperature		-65	150	°C

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 Recommended Operating Conditions⁽¹⁾

			SN	154HCT04		SN	74HCT04		UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNII
V _{CC}	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
V _{IH}	High-level input voltage	V _{CC} = 4.5 V to 5.5 V	2			2			V
V _{IL}	Low-level input voltage	V _{CC} = 4.5 V to 5.5 V			0.8			0.8	V
VI	Input voltage		0		V _{CC}	0		V _{CC}	V
Vo	Output voltage	0		V_{CC}	0		V _{CC}	V	
Δt/Δν	Input transition rise/fall time			500			500	ns	
T _A	Operating free-air temperatu	re	-55		125	-40		85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report Implications of Slow or Floating SMOS Inputs, literature number SCBA004.

5.3 Thermal Information

		D (SOIC)	N (PDIP)	NS (SO)	PW (TSSOP)	
THERMAL	METRIC	14 PINS	14 PINS	14 PINS	14 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽¹⁾	138.7	62.7	90.9	117.6	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	93.8	50.5	48.5	46.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	94.7	42.5	51.5	60.6	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	49.1	30.1	15.9	5.6	°C/W
ΨЈВ	Junction-to-case (bottom) thermal resistance	94.3	42.2	51	60	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

Product Folder Links: SN54HCT04 SN74HCT04

⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



5.4 Electrical Characteristics

	PARAMETER	TEST CONDITIONS(1)	V _{CC}	T,	_A = 25°C		SN54H	CT04	SN74H	CT04	UNIT
	PARAIVIETER	TEST CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
V _{OH}	High-level output voltage	I _{OH} = – 20 μA	4.5	4.4	4.499		4.4		4.4		V
VOH Tright-level output voltage		I _{OH} = – 4 mA	4.5	3.98	4.3		3.7		3.84		V
V _{OL}	Low-level output voltage	I _{OL} = 20 μA	5.5		0.001	0.1		0.1		0.1	V
V _{OL} Low-level output voltage		I _{OL} = 4 mA	5.5		0.17	0.26		0.4		0.33	V
I _I	Input hold current	V _I = V _{CC} or 0	5.5		±0.1	±100		±1000		±1000	nA
Icc	Supply current	$V_I = V_{CC}$ or 0. $I_O = 0$	5.5			2		40		20	μΑ
ΔICC ⁽²⁾	Supply-current change	One input at 0.5V or 2.4 V, Other inputs at 0 or V _{CC}	5.5		1.4	2.4		3		2.9	mA
Ci	Input capacitance		4.5 to 5.5		3	10		10		10	pF

⁽¹⁾ $V_I = V_{IH}$ or V_{IL} , unless otherwise noted.

5.5 Switching Characteristics

C_I = 50 pF. See Parameter Measurement Information

	PARAMETER	EDOM (INDIIT)	то	TO V _{CC}		T _A = 25°C			CT04	SN74HCT04		
FANAMETER	FROM (INPUT)	(OUTPUT)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX		
	Dronagation dolay	A or B	V	4.5		14	20		30		25	no
t _{pd} Propagation delay	AOID	ř	5.5		13	18		27		23	ns	
	Transition time		V	4.5		9	15		22		19	no
t _t Transition time		ř	5.5		8	14		20		17	ns	

5.6 Operating Characteristics

 $T_A = 25^{\circ}C$

			Test Conditions	TYP	UNIT
C	pd	Power dissipation capacitance	No load	20	pF

⁽²⁾ This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or V_{CC}.

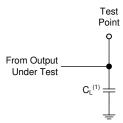


6 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_t < 6 ns.

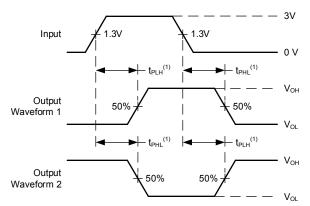
For clock inputs, f_{max} is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.



(1) C_L includes probe and test-fixture capacitance.

Figure 6-1. Load Circuit for Push-Pull Outputs



(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd} .

Figure 6-2. Voltage Waveforms, Propagation Delays for TTL-Compatible Inputs

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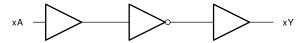


7 Detailed Description

7.1 Overview

These devices contain six independent inverters. They perform the Boolean function $Y = \overline{A}$ in positive logic.

7.2 Functional Block Diagram



7.3 Device Functional Modes

Table 7-1. Function Table (each inverter)

Input A	Output Y
Н	L
L	Н

8 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1-µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

9 Layout

9.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC} , whichever makes more sense for the logic function or is more convenient.



10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

10.1 Documentation Support

10.1.1 Related Documentation

10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

10.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-89747012A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 89747012A SNJ54HCT 04FK	Samples
5962-8974701CA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8974701CA SNJ54HCT04J	Samples
5962-8974701VCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8974701VC A SNV54HCT04J	Samples
5962-8974701VDA	ACTIVE	CFP	W	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8974701VD A SNV54HCT04W	Samples
JM38510/65751BCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 65751BCA	Samples
M38510/65751BCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 65751BCA	Samples
SN54HCT04J	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	SN54HCT04J	Samples
SN74HCT04D	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 85	HCT04	
SN74HCT04DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	HCT04	Samples
SN74HCT04DRE4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT04	Samples
SN74HCT04DRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT04	Samples
SN74HCT04DT	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 85	HCT04	
SN74HCT04N	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74HCT04N	Samples
SN74HCT04NE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74HCT04N	Samples
SN74HCT04NSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT04	Samples
SN74HCT04PW	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 85	HT04	
SN74HCT04PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	HT04	Samples
SN74HCT04PWT	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 85	HT04	



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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SNJ54HCT04FK	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 89747012A SNJ54HCT 04FK	Samples
SNJ54HCT04J	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8974701CA SNJ54HCT04J	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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OTHER QUALIFIED VERSIONS OF SN54HCT04, SN54HCT04-SP, SN74HCT04:

Catalog: SN74HCT04, SN54HCT04

● Enhanced Product : SN74HCT04-EP, SN74HCT04-EP

• Military : SN54HCT04

• Space : SN54HCT04-SP

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

• Military - QML certified for Military and Defense Applications

• Space - Radiation tolerant, ceramic packaging and qualified for use in Space-based application



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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HCT04DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HCT04DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HCT04DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HCT04DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HCT04NSR	so	NS	14	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1
SN74HCT04NSR	so	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74HCT04PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HCT04PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HCT04DR	SOIC	D	14	2500	356.0	356.0	35.0
SN74HCT04DR	SOIC	D	14	2500	356.0	356.0	35.0
SN74HCT04DRG4	SOIC	D	14	2500	356.0	356.0	35.0
SN74HCT04DRG4	SOIC	D	14	2500	353.0	353.0	32.0
SN74HCT04NSR	so	NS	14	2000	356.0	356.0	35.0
SN74HCT04NSR	so	NS	14	2000	356.0	356.0	35.0
SN74HCT04PWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74HCT04PWR	TSSOP	PW	14	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-89747012A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-8974701VDA	W	CFP	14	25	506.98	26.16	6220	NA
SN74HCT04N	N	PDIP	14	25	506	13.97	11230	4.32
SN74HCT04N	N	PDIP	14	25	506	13.97	11230	4.32
SN74HCT04NE4	N	PDIP	14	25	506	13.97	11230	4.32
SN74HCT04NE4	N	PDIP	14	25	506	13.97	11230	4.32
SNJ54HCT04FK	FK	LCCC	20	55	506.98	12.06	2030	NA



SMALL OUTLINE INTEGRATED CIRCUIT



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



W (R-GDFP-F14)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14



8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
 Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
 Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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